

Vishay Siliconix

N-Channel 30-V (D-S) Fast Switching MOSFET

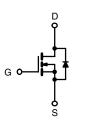
PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
30	0.0065 at V _{GS} = 10 V	21		
	0.008 at V _{GS} = 4.5 V	19		

FEATURES

- · Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET
- New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile
- 100 % R_g Tested

APPLICATIONS

- **DC/DC** Converters
- Optimized for "Low-Side" Synchronous Rectifier Operation



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage		V _{GS}	± 20			
Continuous Drain Current (T _{.1} = 150°C) ^a	T _A = 25°C	- I _D	21	12		
Continuous Drain Current $(1_j = 150 \text{ C})$	T _A = 70°C		17	9	А	
Pulsed Drain Current		I _{DM}	60		A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	4.3	1.6		
Maximum Power Dissipation ^a	T _A = 25°C	– P _D	5.4	1.9	W	
	T _A = 70°C		3.4	1.2		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) ^{b, c}			260			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lungtion to Archienta	t ≤ 10 s	R _{thJA}	18	23	°C/W
Maximum Junction-to-Ambient ^a	Steady State		52	65	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.0	1.3	

Notes

a. Surface Mounted on 1" x 1" FR4 board.

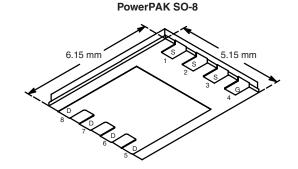
b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.



HALOGEN FREE

Available



Bottom View

Ordering Information: Si7440DP-T1-E3 (Lead (Pb)-free) Si7440DP-T1-GE3 (Lead (Pb)-free and Halogen-free)



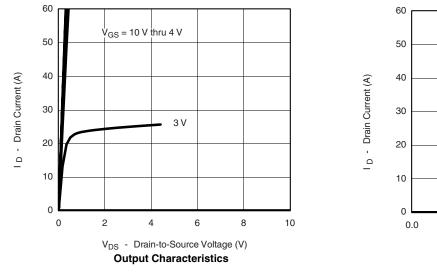
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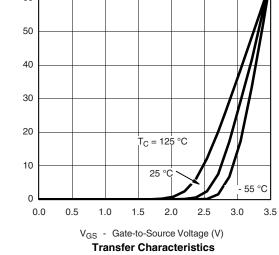
MOSFET SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1.0		3.0	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA		
	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$		1			
Zero Gate Voltage Drain Current		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			5	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			А		
Drain-Source On-State Resistance ^a	Б	V _{GS} = 10 V, I _D = 21 A		0.0053	0.0065	0		
	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 19 A		0.0065	0.008	Ω		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 21 \text{ A}$		65		S		
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S} = 4.3$ A, $V_{\rm GS} = 0$ V		0.72	1.2	V		
Dynamic ^b								
Total Gate Charge	Qg			29.0	35	nC		
Gate-Source Charge	Q _{gs}	Q_{gs} V _{DS} = 15 V, V _{GS} = 4.5 V, I _D = 21 A		10.5				
Gate-Drain Charge	Q _{gd}			10.0				
Gate Resistance	Rg		0.5	1.4	2.2	Ω		
Turn-On Delay Time	t _{d(on)}			18	28			
Rise Time	$\label{eq:constraint} \begin{array}{c} t_r & V_{DD} = 15 \text{ V}, \text{ R}_L = 15 \ \Omega \\ \hline t_{d(off)} & \text{I}_D \cong 1.0 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_g = 6 \ \Omega \end{array}$		16	25				
Turn-Off Delay Time		$\text{I}_{\text{D}}\cong$ 1.0 A, V_{GEN} = 10 V, R_{g} = 6 Ω		75	180	ns		
Fall Time	t _f			41	65			
Source-Drain Reverse Recovery Time	t _{rr}	I_F = 4.3 A, dI/dt = 100 A/µs		50	80			

Notes a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

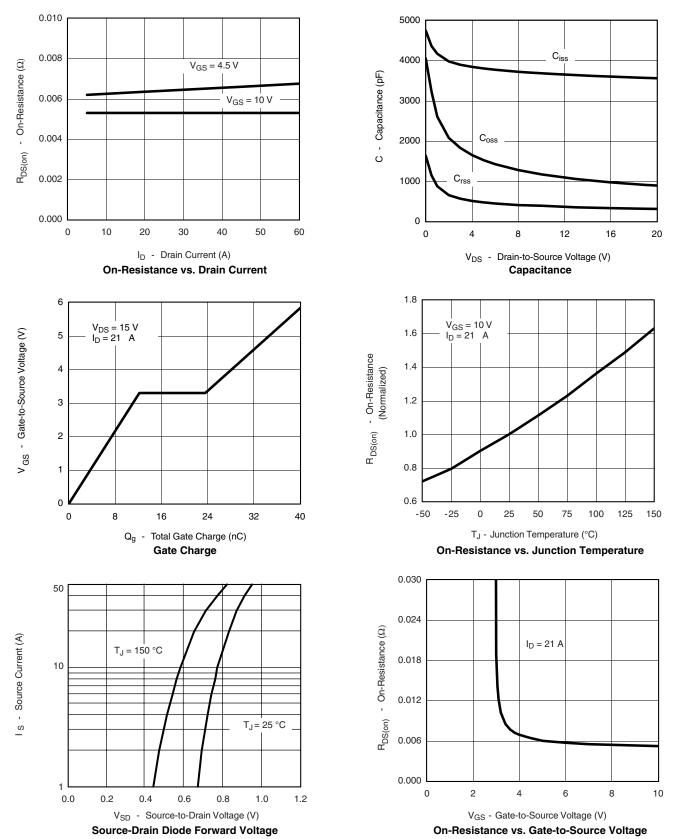




Si7440DP Vishay Siliconix



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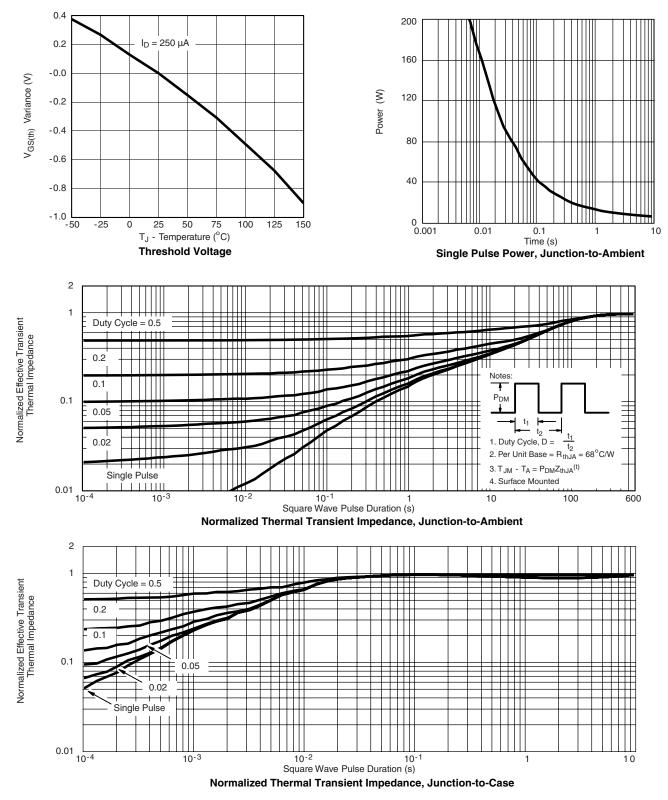
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Si7440DP

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71623.

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